



# BUK6D230-80E

80 V, N-channel Trench MOSFET

29 April 2019

Product data sheet

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Extended temperature range  $T_j = 175\text{ °C}$
- Side wettable flanks for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 2 kV HBM (class H2)
- Trench MOSFET technology
- AEC-Q101 qualified

## 3. Applications

- LED lighting
- High-speed line driver
- Low-side load switch
- Switching circuits

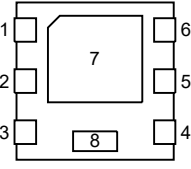
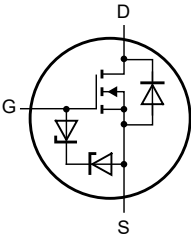
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$T_j = 25\text{ °C}$	-	-	80	V
$V_{GS}$	gate-source voltage		-20	-	20	V
$I_D$	drain current	$V_{GS} = 10\text{ V}; T_{sp} = 25\text{ °C}$	-	-	5.1	A
$P_{tot}$	total power dissipation	$T_{sp} = 25\text{ °C}$	-	-	15	W
<b>Static characteristics</b>						
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 1.9\text{ A}; T_j = 25\text{ °C}$	-	175	230	m $\Omega$

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	 <p>Transparent top view DFN2020MD-6 (SOT1220)</p>	 <p>017aaa255</p>
2	D	drain		
3	G	gate		
4	S	source		
5	D	drain		
6	D	drain		
7	D	drain		
8	S	source		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK6D230-80E	DFN2020MD-6	plastic, leadless thermal enhanced ultra thin small outline package; 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220

## 7. Marking

Table 4. Marking codes

Type number	Marking code
BUK6D230-80E	4T

## 8. Limiting values

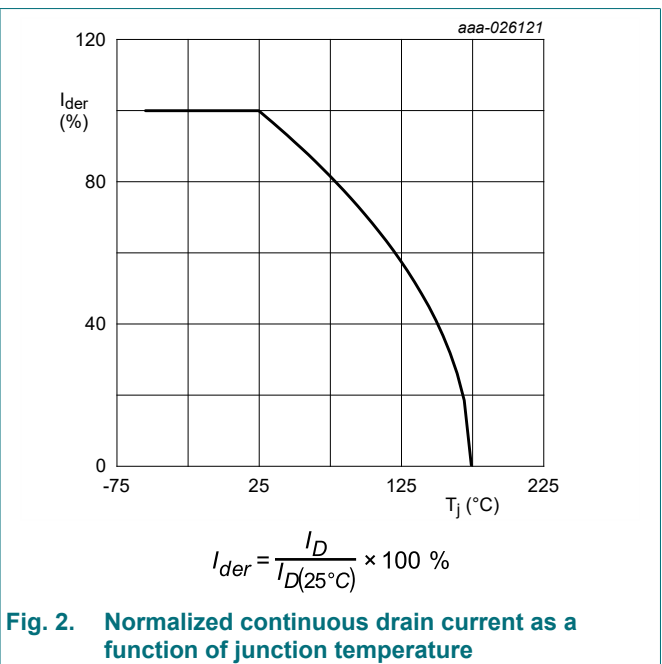
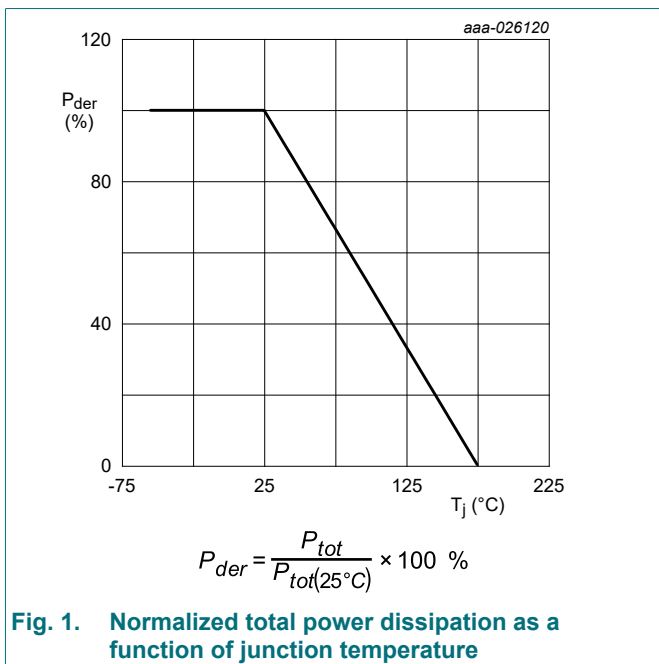
**Table 5. Limiting values**

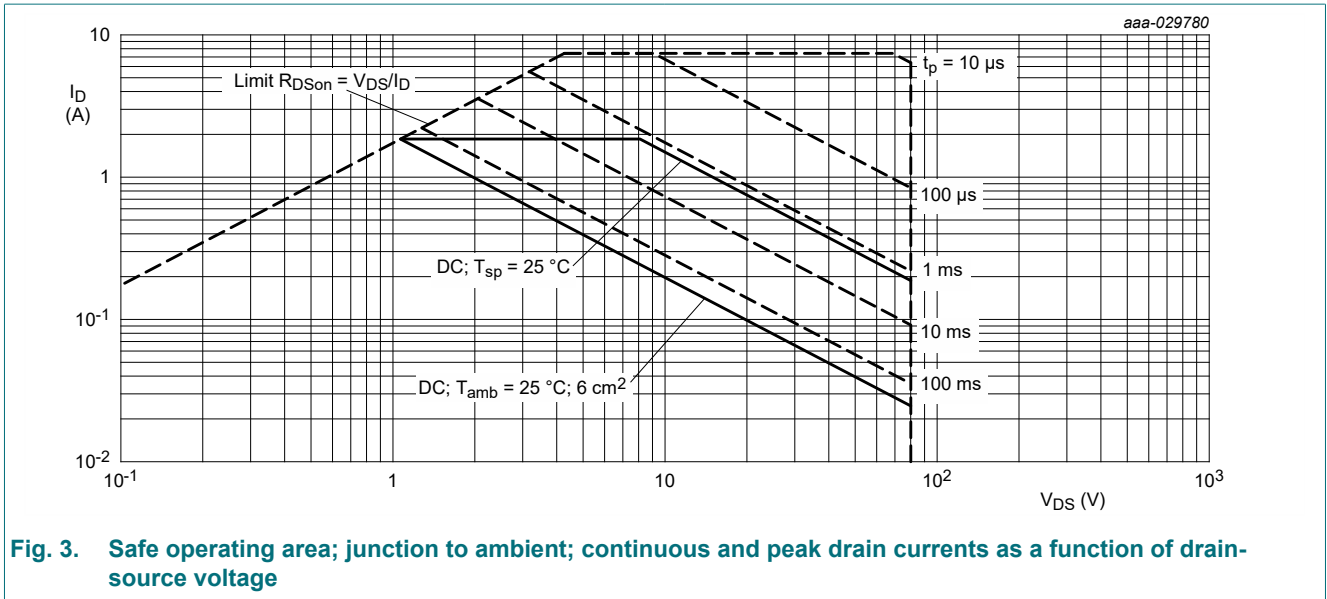
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C	-	80	V
V <sub>GS</sub>	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 25 °C	-	5.1	A
		V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 100 °C	-	3.6	A
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	1.9	A
I <sub>DM</sub>	peak drain current	T <sub>sp</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs	-	20.4	A
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 25 °C	-	15	W
		T <sub>amb</sub> = 25 °C	[1]	2	W
T <sub>j</sub>	junction temperature		-55	175	°C
T <sub>amb</sub>	ambient temperature		-55	175	°C
T <sub>stg</sub>	storage temperature		-65	175	°C
<b>Source-drain diode</b>					
I <sub>S</sub>	source current	T <sub>sp</sub> = 25 °C	-	5.1	A
		T <sub>amb</sub> = 25 °C	[1]	1.9	A
I <sub>SM</sub>	peak source current	single pulse; t <sub>p</sub> ≤ 10 μs; T <sub>sp</sub> = 25 °C	-	20.4	A
<b>ESD maximum rating</b>					
V <sub>ESD</sub>	electrostatic discharge voltage	HBM	[2]	2000	V
<b>Avalanche ruggedness</b>					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = 0.27 A; DUT in avalanche (unclamped)	-	11.3	mJ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

[2] Measured between all pins.





## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	66	76	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	5	10	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

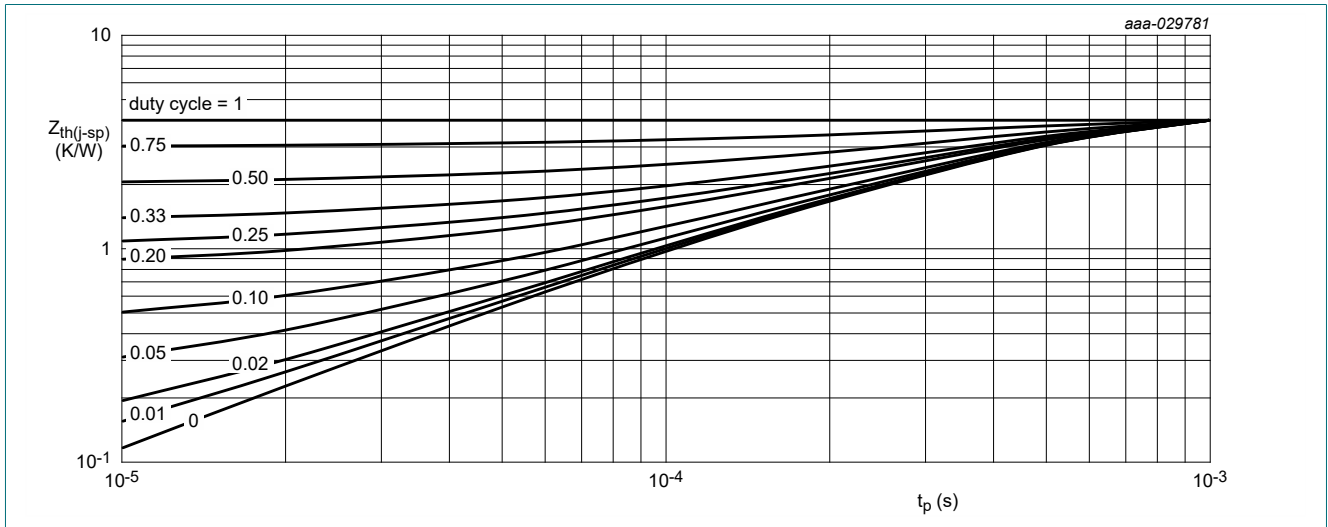


Fig. 4. Transient thermal impedance from junction to solder point as a function of pulse duration; typical values

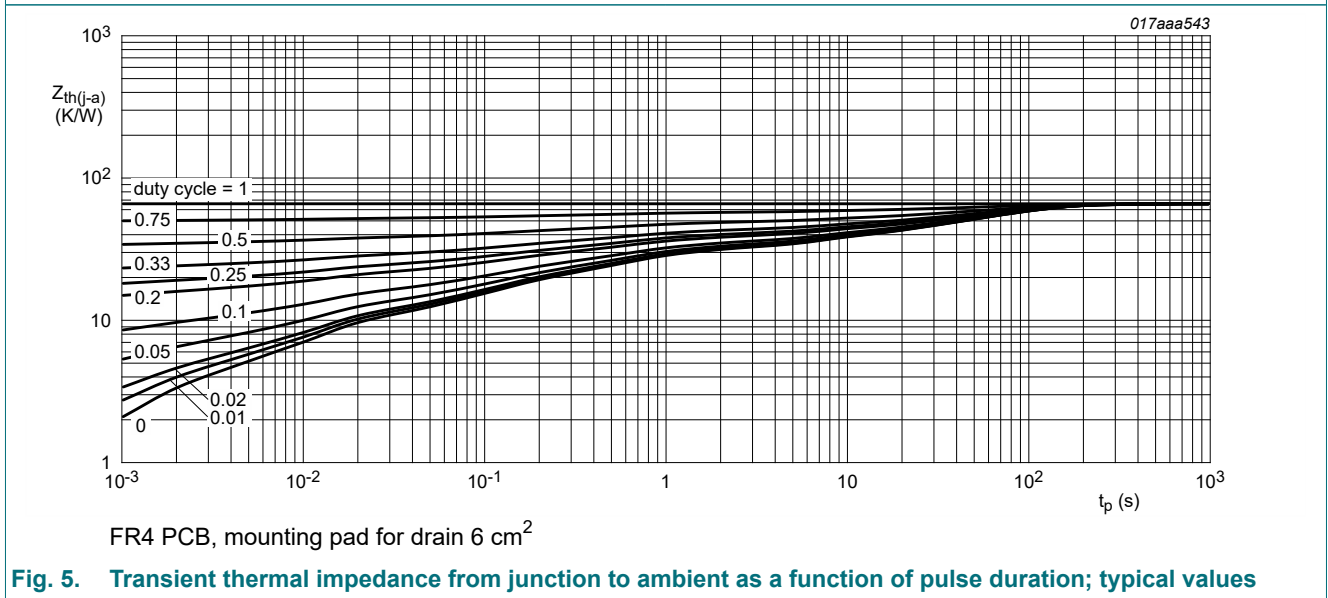
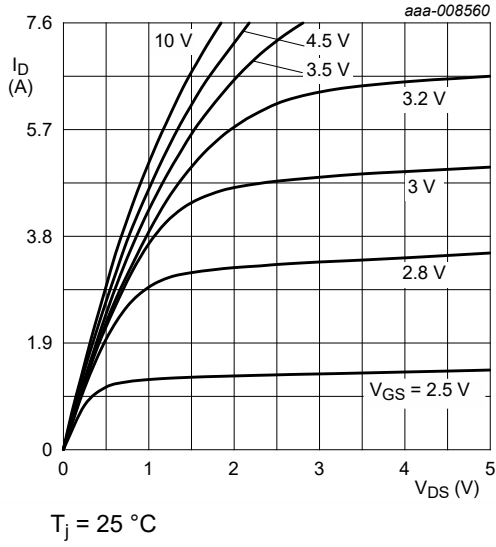


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

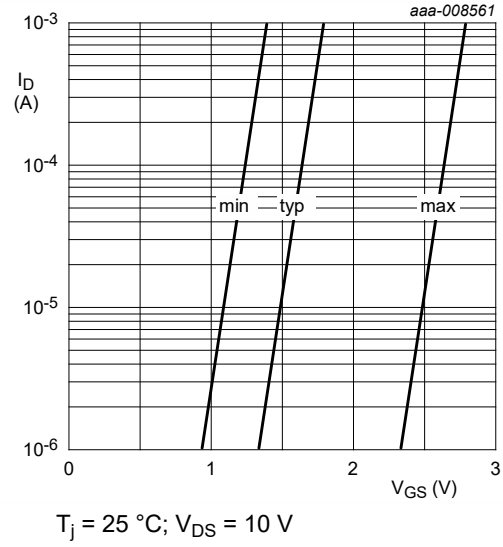
## 10. Characteristics

Table 7. Characteristics

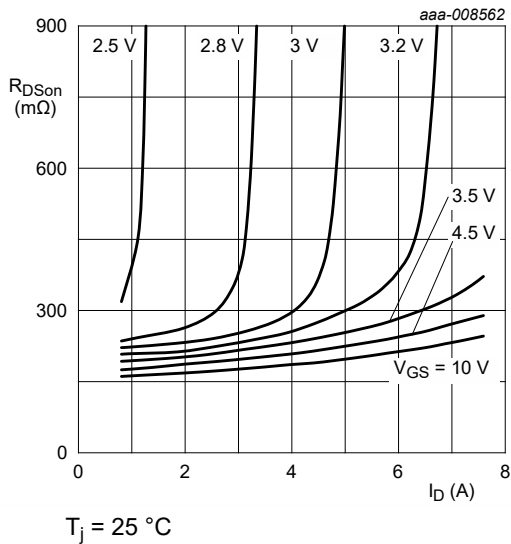
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	80	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \mu A$ ; $V_{DS} = V_{GS}$ ; $T_j = 25^\circ C$	1.3	1.7	2.7	V
$I_{DSS}$	drain leakage current	$V_{DS} = 80 V$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	-	1	$\mu A$
		$V_{DS} = 80 V$ ; $V_{GS} = 0 V$ ; $T_j = 125^\circ C$	-	-	4	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	15	$\mu A$
		$V_{GS} = -20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	-15	$\mu A$
		$V_{GS} = 10 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	1	$\mu A$
		$V_{GS} = -10 V$ ; $V_{DS} = 0 V$ ; $T_j = 25^\circ C$	-	-	-1	$\mu A$
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10 V$ ; $I_D = 1.9 A$ ; $T_j = 25^\circ C$	-	175	230	m $\Omega$
		$V_{GS} = 10 V$ ; $I_D = 1.9 A$ ; $T_j = 175^\circ C$	-	440	575	m $\Omega$
		$V_{GS} = 4.5 V$ ; $I_D = 1.7 A$ ; $T_j = 25^\circ C$	-	195	275	m $\Omega$
$g_{fs}$	forward transconductance	$V_{DS} = 10 V$ ; $I_D = 1.9 A$ ; $T_j = 25^\circ C$	-	7	-	S
$R_G$	gate resistance	$f = 1 MHz$	-	1	-	$\Omega$
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$V_{DS} = 40 V$ ; $I_D = 1.9 A$ ; $V_{GS} = 10 V$ ; $T_j = 25^\circ C$	-	4.8	7.2	nC
$Q_{GS}$	gate-source charge		-	0.6	-	nC
$Q_{GD}$	gate-drain charge		-	0.9	-	nC
$C_{iss}$	input capacitance	$V_{DS} = 40 V$ ; $f = 1 MHz$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	215	-	pF
$C_{oss}$	output capacitance		-	25	-	pF
$C_{rss}$	reverse transfer capacitance		-	15	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 40 V$ ; $I_D = 1.9 A$ ; $V_{GS} = 10 V$ ; $R_{G(ext)} = 6 \Omega$ ; $T_j = 25^\circ C$	-	3.5	-	ns
$t_r$	rise time		-	2	-	ns
$t_{d(off)}$	turn-off delay time		-	9.5	-	ns
$t_f$	fall time		-	3	-	ns
<b>Source-drain diode</b>						
$V_{SD}$	source-drain voltage	$I_S = 1.9 A$ ; $V_{GS} = 0 V$ ; $T_j = 25^\circ C$	-	0.8	1.2	V
$t_{rr}$	reverse recovery time	$I_S = 1.8 A$ ; $di_S/dt = -100 A/\mu s$ ;	-	16	-	ns
$Q_r$	recovered charge	$V_{GS} = 0 V$ ; $V_{DS} = 40 V$ ; $T_j = 25^\circ C$	-	7.6	-	nC



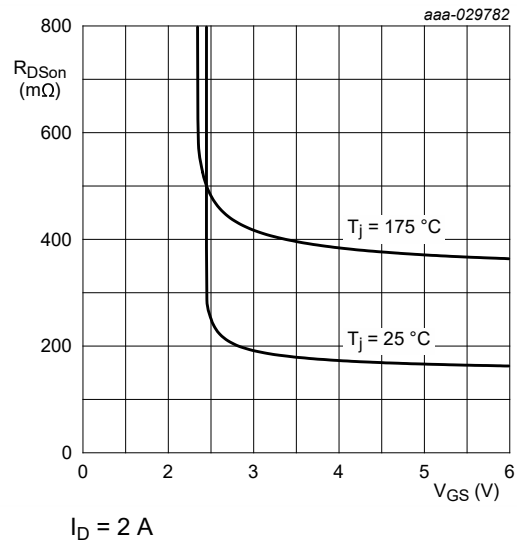
**Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values**



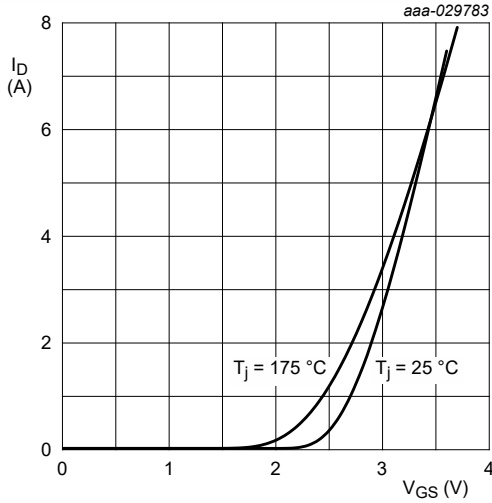
**Fig. 7. Sub-threshold drain current as a function of gate-source voltage**



**Fig. 8. Drain-source on-state resistance as a function of drain current; typical values**

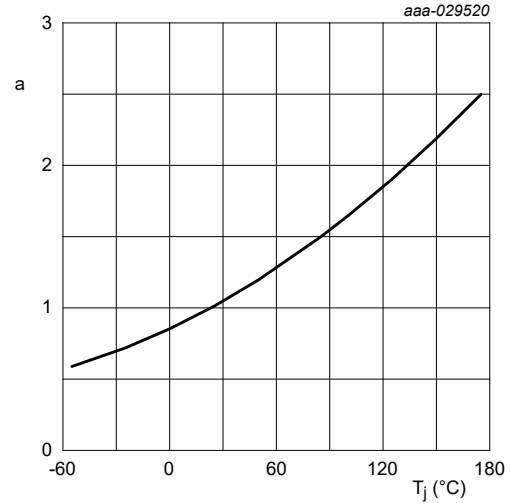


**Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values**



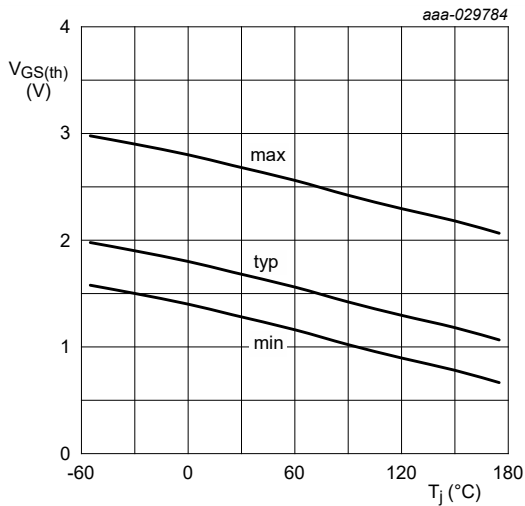
$$V_{DS} > I_D \times R_{DSon}$$

Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values



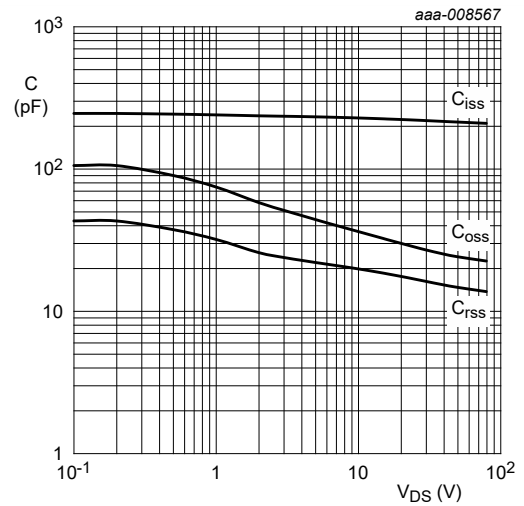
$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ C)}$$

Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values



$$I_D = 250 \mu A; V_{DS} = V_{GS}$$

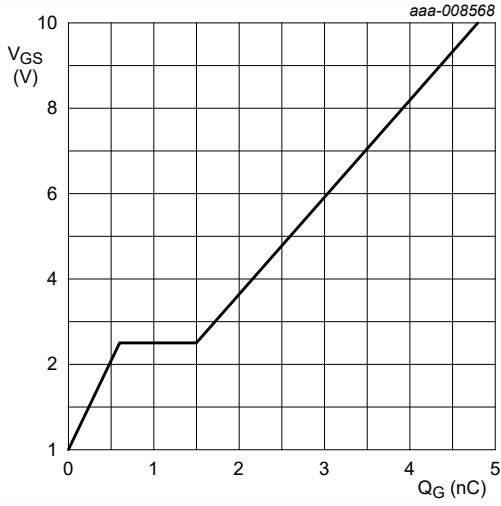
Fig. 12. Gate-source threshold voltage as a function of junction temperature



$$f = 1 \text{ MHz}; V_{GS} = 0 \text{ V}$$

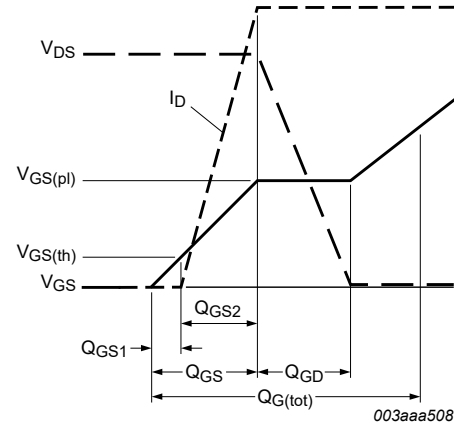
Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



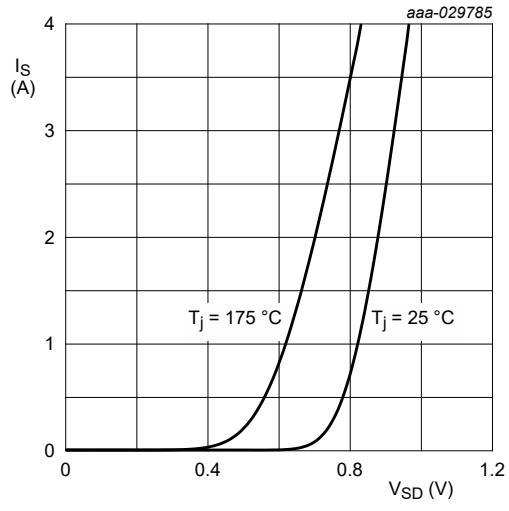


$I_D = 1.9 \text{ A}$ ;  $V_{DS} = 40 \text{ V}$ ;  $T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig. 14. Gate-source voltage as a function of gate charge; typical values**



**Fig. 15. Gate charge waveform definitions**



$V_{GS} = 0 \text{ V}$

**Fig. 16. Source current as a function of source-drain voltage; typical values**

## 11. Test information

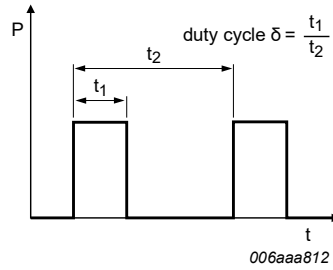


Fig. 17. Duty cycle definition

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body 2 x 2 x 0.65 mm

SOT1220

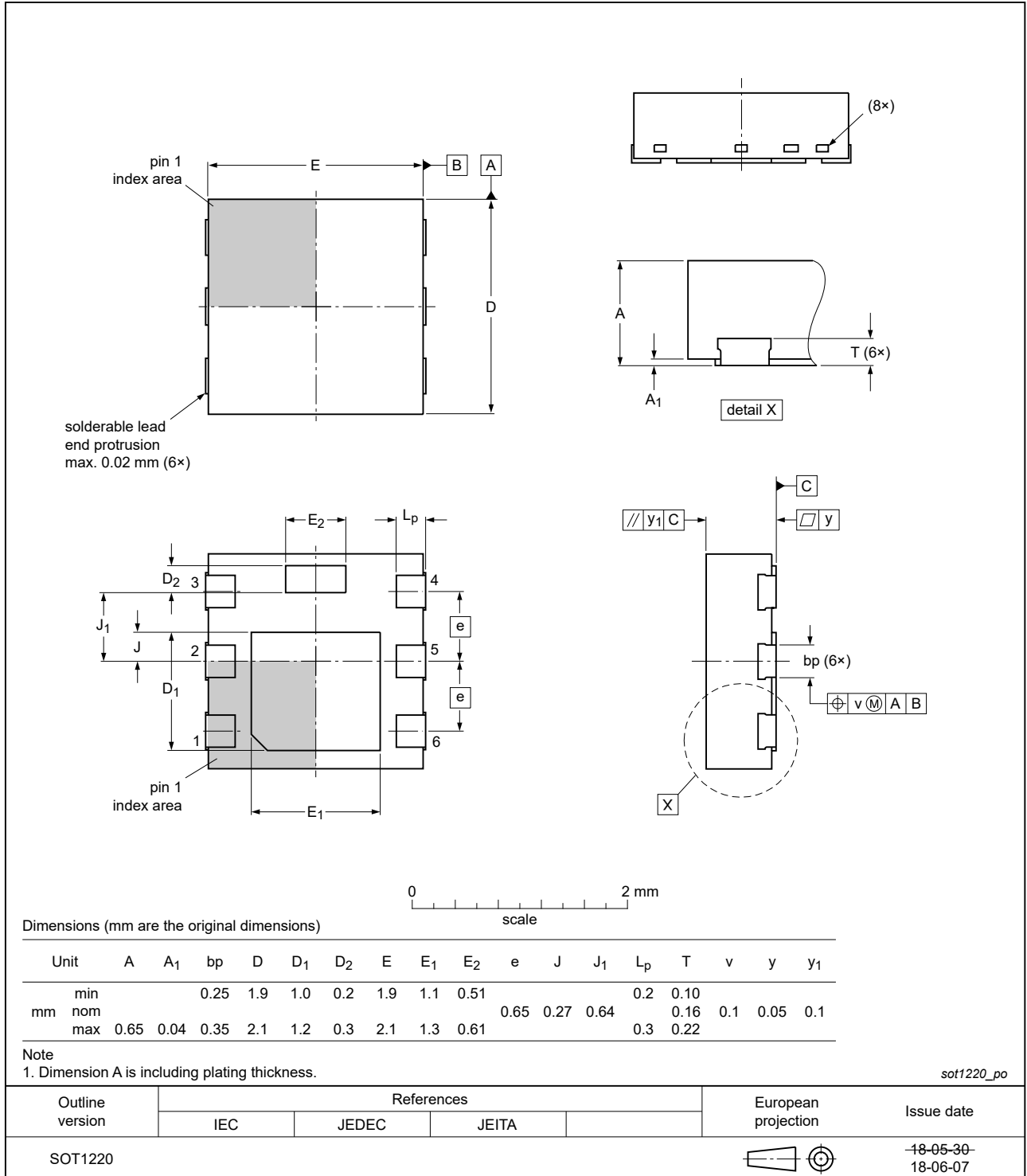


Fig. 18. Package outline DFN2020MD-6 (SOT1220)

### 13. Soldering

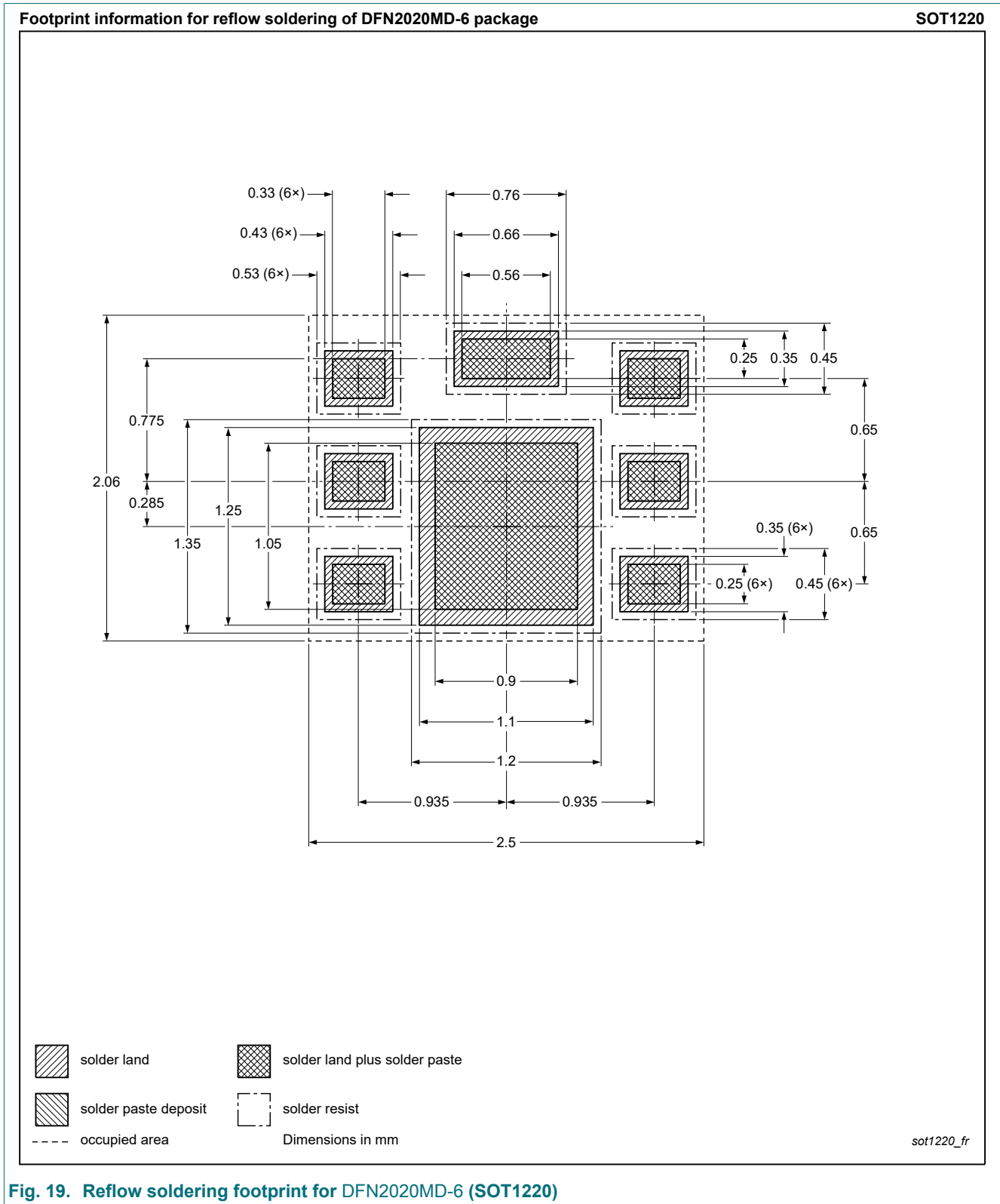


Fig. 19. Reflow soldering footprint for DFN2020MD-6 (SOT1220)

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK6D230-80E v.1	20190429	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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